

## Vishay Telefunken

## Silicon PIN Photodiode

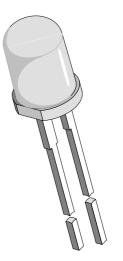
## **Description**

BPW43 is a very high speed PIN photodiode in a standard T-13/4 plastic package. Due to its waterclear epoxy the device is sensitive to visible and infrared radiation.

It features low capacitance and high speed even at low supply voltages.

#### **Features**

- Extra fast response times
- Radiant sensitive area A=0.78mm<sup>2</sup>
- Standard T-13/4 (ø 5 mm) clear package
- Angle of half sensitivity  $\varphi = \pm 25^{\circ}$
- Suitable for visible and near infrared radiation



94 8391

#### **Applications**

High speed photo detector

## **Absolute Maximum Ratings**

 $T_{amb} = 25^{\circ}C$ 

| Parameter                           | Test Conditions          | Symbol            | Value           | Unit |
|-------------------------------------|--------------------------|-------------------|-----------------|------|
| Reverse Voltage                     |                          | $V_{R}$           | 32              | V    |
| Power Dissipation                   | T <sub>amb</sub> ≤ 25 °C | $P_V$             | 215             | mW   |
| Junction Temperature                |                          | T <sub>i</sub>    | 100             | °C   |
| Storage Temperature Range           |                          | T <sub>stg</sub>  | <i>−</i> 25+100 | °C   |
| Soldering Temperature               | t ≦ 3 s                  | T <sub>sd</sub>   | 245             | °C   |
| Thermal Resistance Junction/Ambient |                          | R <sub>thJA</sub> | 350             | K/W  |

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#### **Basic Characteristics**

 $T_{amb} = 25^{\circ}C$ 

| Parameter                      | Test Conditions   | Symbol           | Min | Тур     | Max | Unit |
|--------------------------------|---|------------------|-----|---------|-----|------|
| Breakdown Voltage              | $I_R = 100  \mu A,  E = 0$  | $V_{(BR)}$       | 32  |         |     | V    |
| Reverse Dark Current           | $V_R = 10 \text{ V, E} = 0$   | Ì <sub>ro</sub>  |     | 1       | 10  | nA   |
| Diode Capacitance              | $V_R = 0 V, f = 1 MHz, E = 0$   | $C_D$            |     | 4       |     | рF   |
|                                | $V_R = 5 \text{ V, } f = 1 \text{ MHz, } E = 0$                                 | $C_D$            |     | 1.5     |     | рF   |
|                                | $V_R = 10 \text{ V, } f = 1 \text{ MHz, } E = 0$                                | $C_{D}$          |     | 1.3     |     | рF   |
| Open Circuit Voltage           | $E_A = 1 \text{ klx}$   | V <sub>o</sub>   |     | 320     |     | mV   |
| Short Circuit Current          | $E_A = 1 \text{ klx}$   | l <sub>k</sub>   |     | 12      |     | μΑ   |
|                                | $E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$                             | l <sub>k</sub>   |     | 6       |     | μΑ   |
| Reverse Light Current          | $E_A = 1 \text{ klx}, V_R = 5 \text{ V}$  | I <sub>ra</sub>  |     | 15      |     | μА   |
|                                | $E_e = 1 \text{ mW/cm}^2$ ,<br>$\lambda = 950 \text{ nm}$ , $V_R = 5 \text{ V}$ | I <sub>ra</sub>  | 4   | 8       |     | μΑ   |
| Angle of Half Sensitivity      |   | φ                |     | ±25     |     | deg  |
| Wavelength of Peak Sensitivity |   | $\lambda_{p}$    |     | 900     |     | nm   |
| Range of Spectral Bandwidth    |   | λ <sub>0.5</sub> |     | 5501000 |     | nm   |
| Rise Time                      | $V_R$ = 10 V, $R_L$ = 50 $\Omega$ , $\lambda$ = 820 nm                          | t <sub>r</sub>   |     | 4       |     | ns   |
| Fall Time                      | $V_R = 10 \text{ V}, R_L = 50 \Omega,$<br>$\lambda = 820 \text{ nm}$            | t <sub>f</sub>   |     | 4       |     | ns   |

# **Typical Characteristics** $(T_{amb} = 25^{\circ}C \text{ unless otherwise specified})$

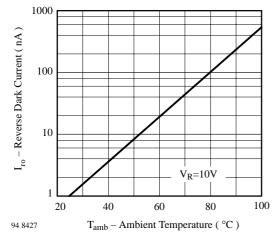


Figure 1. Reverse Dark Current vs. Ambient Temperature

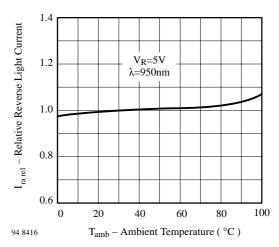


Figure 2. Relative Reverse Light Current vs.
Ambient Temperature



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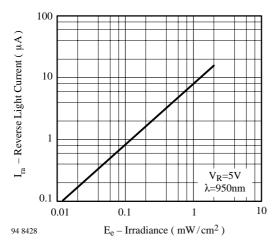


Figure 3. Reverse Light Current vs. Irradiance

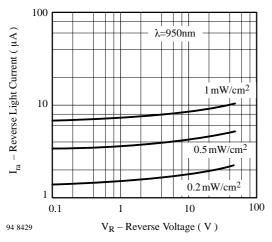


Figure 4. Reverse Light Current vs. Reverse Voltage

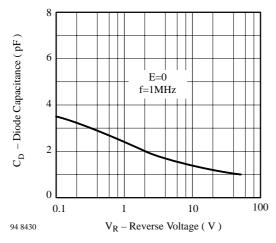


Figure 5. Diode Capacitance vs. Reverse Voltage

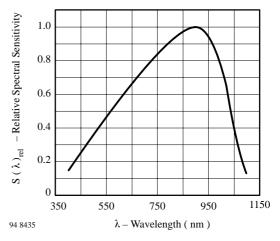


Figure 6. Relative Spectral Sensitivity vs. Wavelength

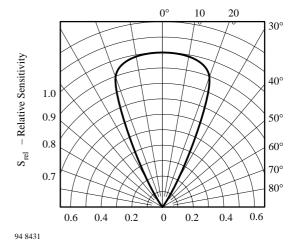


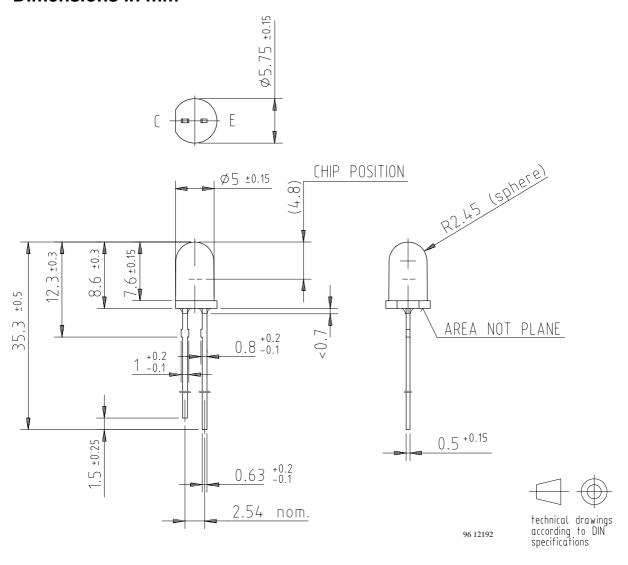
Figure 7. Relative Radiant Sensitivity vs. Angular Displacement

# **BPW43**

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#### **Dimensions in mm**





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#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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